

## Short communication

Influence of additives on nano-SiC whisker formation  
in alumina silicate–SiC–C monolithic refractories

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**Abstract**

This study describes the effect of additives on increasing cold crushing strength (CCS) and bulk density (BD) of alumina silicate–SiC–C monolithic refractories. Two series of carbon-containing monolithics were prepared from Iranian chamotte (sample A) and Chinese bauxite (sample B), as 65 wt.% in each case together with, 15 wt.% SiC-containing material regenerates (crushed sagger) and 10 wt.% fine coke (a total of 90% aggregate) and 10 wt.% resole (phenol formaldehyde resin) as binder. Different values of additives (such as silicon and ferrosilicon metal) are added to the mixture and BD, apparent porosity and CCS are measured after tempering at 200 °C for 2 h and firing at 1100 °C and 1400 °C for 2 h. At low temperature of 200 °C, Si and ferrosilicon contribute to the formation of stronger cross-linking in the resit structure and provide CCS values of as high as about 65 MPa. At 1400 °C, SiC whiskers of nano-sized diameter are formed due to the presence of Si and FeSi<sub>2</sub> and improve CCS values of as high as about 3–4 times in sample containing 6 wt.% ferrosilicon metal as additive.

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**Keywords:** B. Whiskers; C. Strength; D. Al<sub>2</sub>O<sub>3</sub>; E. Refractories**1. Introduction**

The development of alumina silicate–SiC–C resole bonded ramming monolithic refractory for iron making application (such as iron and slag runner in blast furnaces, furnace bottom and electric-furnace spouts) [1] is a very important recent refractory development which can be considered as evolved from the high performance chamotte–carbon and bauxite–carbon refractories. This class of refractories not only shows superior slag corrosion and erosion (wear) resistance, but also excellent thermal shock and mechanical properties. Monolithic refractories containing bauxite aggregate has shown higher densification and mechanical properties due to the presence of some impurities such as iron which help liquid phase sintering, and consequently, improved mechanical properties [2]. These refractories consist mainly of aluminosilicate and carbon, which are bonded by carbon bonds formed by carbonization of phenol formaldehyde resin (resole) during firing of the refractories [1,3].

Carbon does not been wet by molten metal and will not melt, that is an advantage excellent for refractory use. Its great weakness is that it will oxidize at low temperatures above 600 °C, which creates high porosity, lower density and reduced strength [1,4]. In order to improve the oxidation resistance of carbon-containing refractories, the so-called antioxidants (such as aluminum and silicon metal) have been often added [5]. However, by examining the behavior of Al in the refractories, low melting point Al particles, decrease refractoriness and the reaction of Al and water, limits its use with water-containing binders. Based on the above consideration, it is necessary to develop new antioxidants with excellent hydration resistance and high melting point such as Si-containing antioxidants. Effect of metallic silicon size on properties of alumina–carbon brick is studied, and reported that the added metallic silicon reacts under the reducing atmosphere with carbon in the brick and produces so-called β-SiC bond which contributes to improvements of the mechanical strength and the abrasion resistance under oxidation. The influence of β-SiC bond to the mechanical strength has not been clarified [6].

Generally, modulus of rupture vs. firing temperature is increased and at a given temperature (1100, 1200, 1300, 1500 °C) by increasing particle size of silicon up to more than

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Table 2  
Phase analysis of raw materials (XRD results).

Material	Major phase	Medium phase	Minor phase (s)
Chinese bauxite	$\text{Al}_2\text{O}_3\alpha$	Mullite ( $3\text{Al}_2\text{O}_3 \cdot 2\text{SiO}_2$ )	$\text{TiO}_2$ , $\text{SiO}_2$
Iranian chamotte	Mullite ( $3\text{Al}_2\text{O}_3 \cdot 2\text{SiO}_2$ )	—	Cristobalite ( $\text{SiO}_2$ )
Crushed sagger	$\text{SiC}\alpha$ —	Mullite ( $3\text{Al}_2\text{O}_3 \cdot 2\text{SiO}_2$ )	$\text{Al}_2\text{O}_3\alpha$
Fine coke	Graphite	—	$\text{Al}_2\text{O}_3$ , $\text{SiO}_2$
Ferrosilicon metal	$\text{FeSi}_2$	Si	—
Silicon metal	Si	—	—

where  $W$ ,  $W_s$  and  $W_f$ , respectively, are the weight of dried sample, saturated weight with water and weight of the sample in water suspended by a thin thread without contacting the vessel walls, but fully inside the water and reading by a digital balance under the vessel. In fact  $W_f$  is the weight reduction of saturated sample in the water which is equivalent to its volume.

An X-ray diffraction (XRD) instrument (Philips Xpert-MPD System) with  $\text{Cu K}\alpha_1$  ( $\lambda_1 = 1.5405 \text{ \AA}$ ) and  $\text{Cu K}\alpha_2$  ( $\lambda_2 = 1.5443 \text{ \AA}$ ) and Ni filter was used for phase analysis. In order to study precisely the phases, the XRD experiments were carried out with a rate of  $0.04^\circ/\text{s}$  between  $5^\circ$  and  $80^\circ$  ( $2\theta$ ). Scanning electron microscopy (SEM, Philips XL30) was used for microstructure investigations. X-ray fluorescence (XRF) was also used for elemental analysis and oxides content calculations (Table 1).

### 3. Results and discussion

Figs. 2–5 show the influence of additives on cold crushing strength, resole bond, alumina silicate–SiC–C refractory. Figs. 6–8 illustrate BD variations. Figs. 9 and 10 show fired

microstructures at  $1100^\circ\text{C}$  for 2 h. Figs. 11 and 12 show fired microstructures at  $1400^\circ\text{C}$  for 2 h. Phase compositions by XRD results are given in Figs. 13–16.

The effect of additives on sample A containing Iranian chamotte as the main aggregate (65 wt.%) is such that silicon metal and ferrosilicon metal generally increase cold crushing

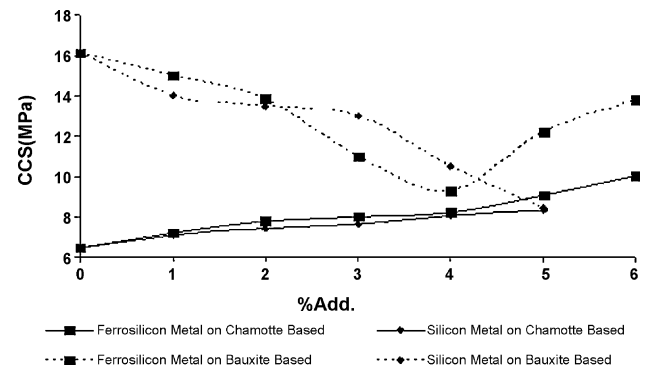


Fig. 4. Effect of additives on CCS of bauxite and chamotte based fired at  $1100^\circ\text{C}$  for 2 h.

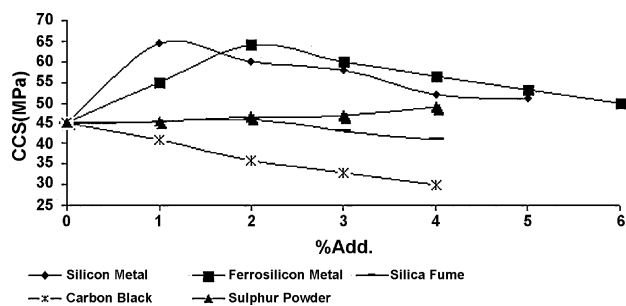


Fig. 2. Effect of additives on CCS of chamotte based cured at  $200^\circ\text{C}$  for 2 h (sample A).

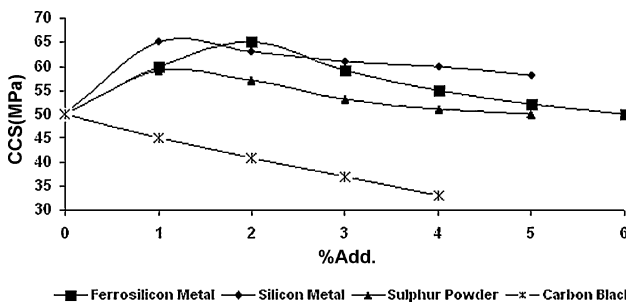


Fig. 3. Effect of additives on CCS of bauxite based cured at  $200^\circ\text{C}$  for 2 h (sample B).

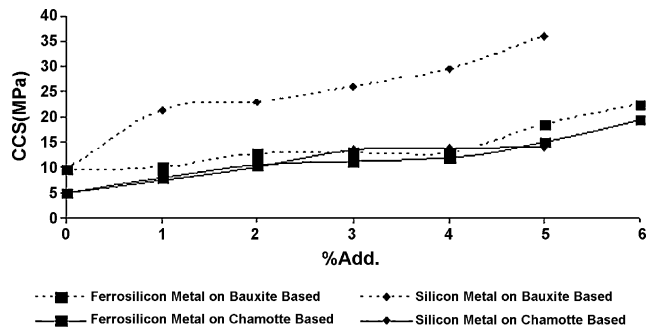


Fig. 5. Effect of additives on CCS of bauxite and chamotte based fired at  $1400^\circ\text{C}$  for 2 h.

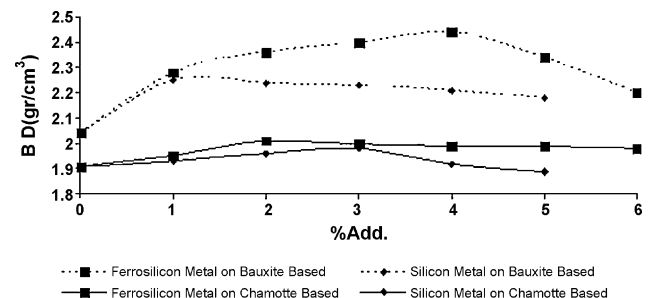


Fig. 6. Effect of additives on BD of chamotte and bauxite based cured at  $200^\circ\text{C}$  for 2 h.

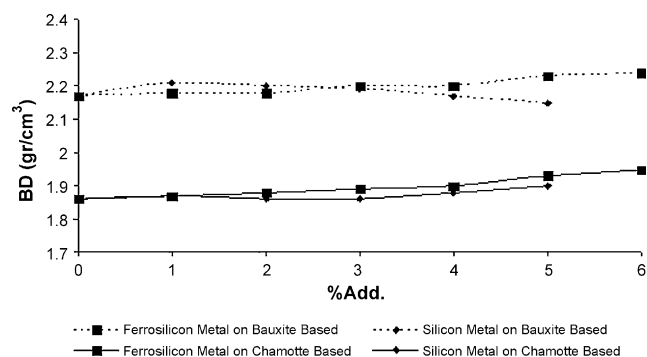


Fig. 7. Effect of additives on BD of chamotte and bauxite based fired at 1100 °C for 2 h.

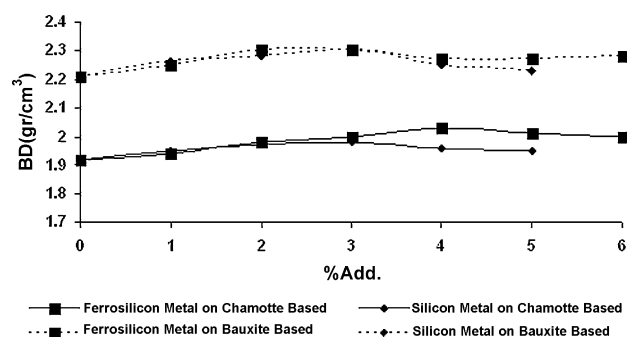


Fig. 8. Effect of additives on BD of chamotte and bauxite based fired at 1400 °C for 2 h.

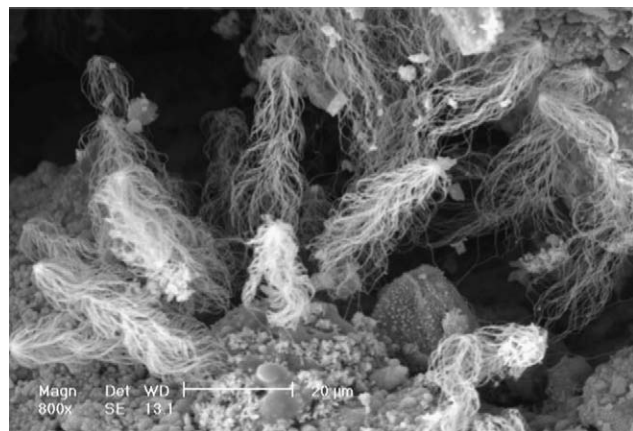


Fig. 9. Micrograph of chamotte-carbon refractory resole bond containing 6 wt.% ferrosilicon metal as additive, fired at 1100 °C, small quantities of SiC whisker are observed.

strength at all heat treatments of 200 °C, 1100 °C and 1400 °C, also increase bulk density. Sample B based on Chinese bauxite also shows CCS increase at 200 °C and 1400 °C, but CCS is reduced at 1100 °C. SEM photomicrographs have proved that SiC whiskers of nano-sized diameter has developed in sample A, but not in sample B at 1100 °C. The reason for increase of strength in sample A, which was not clarified in some cases [5], is now evident to be related to the development of nano-sized whiskers of SiC.

The reason to develop only in sample A, might depend on higher amount of mullite and glassy phase in chamotte with

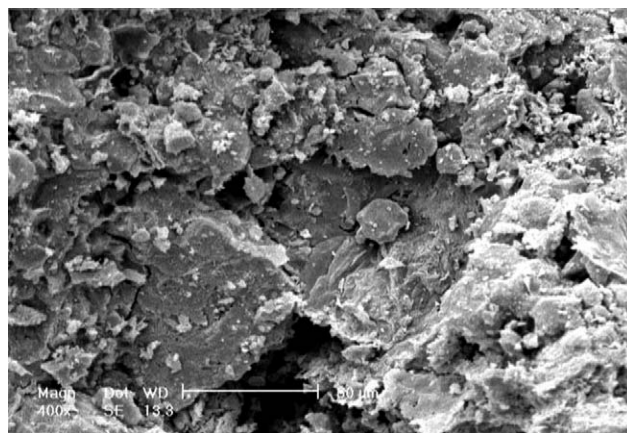


Fig. 10. Micrograph of bauxite-carbon refractory resole bond containing 5 wt.% silicon metal as additive, fired at 1100 °C, shows that no SiC whisker is formed.

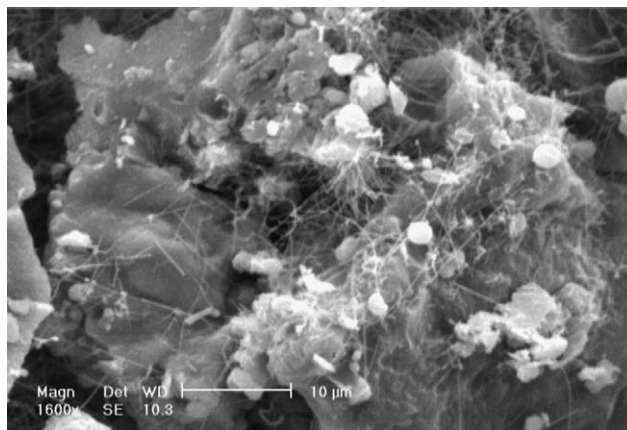


Fig. 11. Micrograph of chamotte-carbon refractory resole bond containing 6 wt.% ferrosilicon metal as additive, fired at 1400 °C, showing SiC whiskers of about 75 nm in diameter in the microstructure.

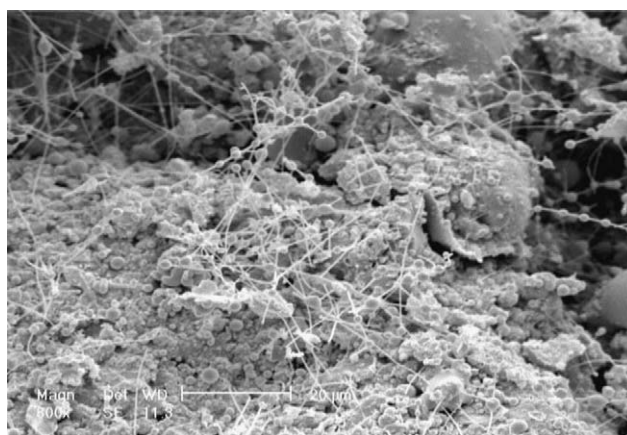


Fig. 12. Micrograph of bauxite-carbon refractory resole bond containing 6 wt.% ferrosilicon metal as additive, fired at 1400 °C, SiC whiskers are developed from ferrosilicon metal particles in the microstructure.

respect to bauxite. Needles of mullite in glassy phase of matrix might be good for nucleation positions for starting and growth of SiC whiskers at low temperature of 1100 °C. At 1400 °C, the driving force is high enough for the production of SiC whiskers



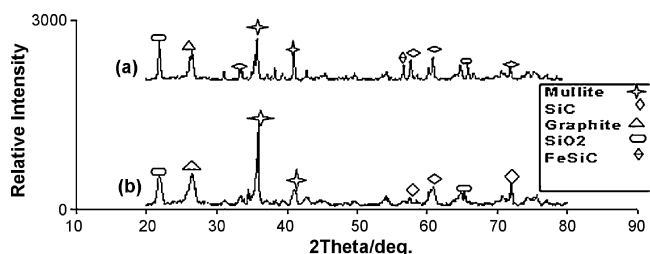


Fig. 13. XRD results of fired chamotte-carbon refractory resole bond fired at 1400 °C for 2 h (a) 6 wt.% ferrosilicon as additive; (b) without additive.

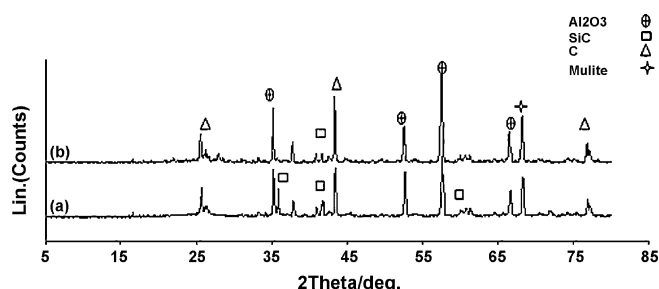


Fig. 14. XRD results of fired bauxite-carbon refractory resole bond fired at 1400 °C for 2 h (a) 5 wt.% silicon as additive; (b) without additive.

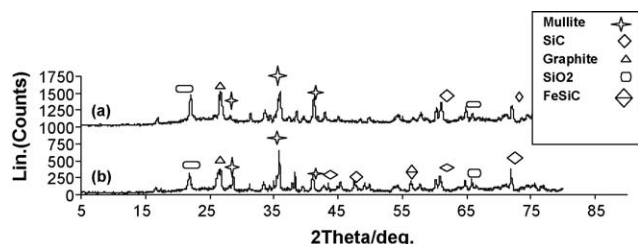


Fig. 15. XRD results of fired chamotte-carbon refractory resole bond fired at 1100 °C for 2 h (a) without additive; (b) 6 wt.% ferrosilicon.

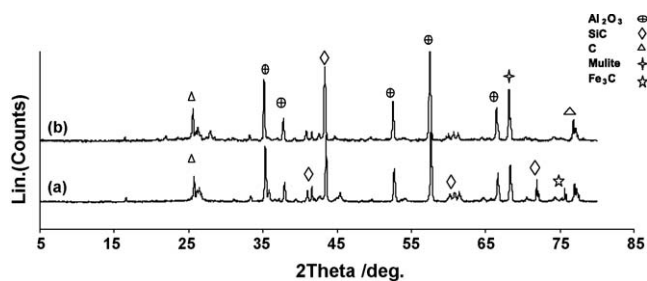
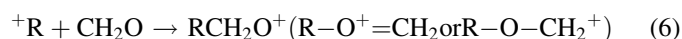
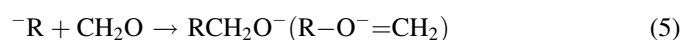


Fig. 16. XRD results of fired bauxite-carbon refractory resole bond fired at 1100 °C for 2 h (a) without additive; (b) 6 wt.% ferrosilicon.

in both samples A and B. But the concentration of whiskers at a comparable level of 6 wt.% ferrosilicon metal ( $\text{FeSi}_2$ ) is more for chamotte matrix (Fig. 11) than bauxite matrix (Fig. 12). It seems that these whisker are formed on chamotte aggregates in Fig. 11, but are nucleated on  $\text{FeSi}_2$  particles in Fig. 12 and outside of bauxite particles. The  $\text{FeSi}_2$  spheres are observed in Fig. 12. These figures might support the hypothesis of SiC whisker formation due to surface tension of glassy matrix and nucleation effect of mullite needles on chamotte aggregates.

The reason of strength increase at high temperatures is evident to be related to the formation of nano-SiC whisker, but

the mechanism for CCS increase at heat treatment of 200 °C is related to the cross-linking formation in phenol formaldehyde resole structure or resit. For this temperature 5 different additions of silicon metal, ferrosilicon metal, sulphur, silica fume and carbon black were used. The first 2 are capable of increasing the cross-linking, but the next 3 were not so effective (Figs. 2 and 3). The Si has a strong effect in small amount of 1 wt.%. By considering Fig. 1, it is probable that formaldehyde ( $\text{CH}_2\text{O}$ ) which act as cross-linking agent of A for the main monomer of phenol ( $\text{C}_6\text{H}_5\text{OH}$ ) is interfered with a lot of Si atoms, each associated with covalent bonds, at the expense of decreasing the cross-links of phenol formaldehyde monomers. Formaldehyde is very reactive and readily polymerizes with ionic initiation [11]. Either anionic or cationic materials can initiate the polymerization reaction.



Ferrosilicon is less effective than silicon and shows a maximum CCS at 2% and reduces the strength for 3% and above. The type of effect is the same. Micro-silica or silica fume (small amorphous spherical particles of  $\text{SiO}_2$ ) and carbon black, amorphous carbon, do not contribute to a stronger cross-linking, probably due to having an amorphous and non-crystalline nature and submicron size of the amorphous particles, but play the interfering effect to reduce CCS. Almost the similar effects are observed when the additives are used in bauxite based refractories of sample B (Fig. 3). Results in samples A and B confirm each other. The role of sulphur in increasing of CCS was good to some extent (Figs. 2 and 3), but not as effective as Si or ferrosilicon. At high temperature of above 800 °C, resit structure is destroyed and graphite phase as a crystalline carbon state is formed. XRD results show higher peaks of graphite phase at 1400 °C firing (Figs. 13 and 14) with respect to 1100 °C firing (Figs. 15 and 16).

#### 4. Conclusions

1. The addition of silicon or ferrosilicon metal to aluminasilicate-carbon ramming monolithics with resole bond for iron making applications, improves mechanical properties and develop high strength and therefore wear resistance for applications such as blast furnace runners and troughs.
2. At low temperature of 200 °C these additions contribute to the formation of resit structure in resole and by increasing the cross-linking provides CCS values of as high as about 65 MPa, which is remarkable for a carbon-containing monolithic.
3. There is a limit of 1 wt.% for silicon and 2 wt.% for ferrosilicon to increase the cross-linking phenomena and raise the strength of the refractory, beyond which the interfering with formaldehyde is performed, effectiveness of cross-linking is reduced and the strength is lowered.
4. Three additives of silica fume, carbon black and sulphur were not so effective as compared with silicon and ferrosilicon metal.

5. SiC whiskers of nano-sized diameter are formed at 1400 °C in both samples containing chamotte and bauxite. At 1100 °C these whiskers are only observed in chamotte based refractory. A hypothesis is given that probably higher glassy content of the matrix of chamotte has caused higher surface tension and higher amounts of needles of mullite in chamotte rather than bauxite, has caused more nucleation of SiC whisker. The temperature of 1100 °C is a transient temperature that cross-linking is destroyed and SiC whisker formation is not fully formed yet.
6. Nano-SiC whiskers are shown in Figs. 9, 11 and 12. They act as reinforcing media to increase the strength of matrix. Fully developed whiskers at 1400 °C can act stronger in reinforcing glassy content matrix than just partially nucleated ones at 1100 °C.
7. In situ SiC whisker formation of both chamotte and bauxite based monolithic offer certain economical advantages with respect to separate production and use of such nano-whiskers.

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